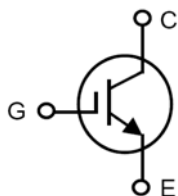
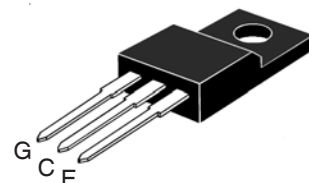


**GenX3™ 600V  
IGBT**
**IXGP28N60A3M**

$$V_{CES} = 600V$$

$$I_{C110} = 15A$$

$$V_{CE(sat)} \leq 1.4V$$

 Ultra Low Vsat PT IGBT for up  
to 5kHz Switching

**OVERMOLDED TO-220**

 G = Gate      C = Collector  
E = Emitter

| Symbol                        | Test Conditions  | Maximum Ratings                          |                  |
|-------------------------------|--|--|------------------|
| $V_{CES}$                     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$  | 600                                      | V                |
| $V_{CGR}$                     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GE} = 1M\Omega$                      | 600                                      | V                |
| $V_{GES}$                     | Continuous   | $\pm 20$                                 | V                |
| $V_{GEM}$                     | Transient  | $\pm 30$                                 | V                |
| $I_{C25}$                     | $T_C = 25^\circ\text{C}$   | 38                                       | A                |
| $I_{C110}$                    | $T_C = 110^\circ\text{C}$  | 15                                       | A                |
| $I_{CM}$                      | $T_C = 25^\circ\text{C}$ , 1ms   | 200                                      | A                |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 10\Omega$<br>Clamped Inductive Load | $I_{CM} = 48$<br>@ $V_{CE} \leq V_{CES}$ | A                |
| $P_C$                         | $T_C = 25^\circ\text{C}$   | 64                                       | W                |
| $T_J$                         |  | -55 ... +150                             | $^\circ\text{C}$ |
| $T_{JM}$                      |  | 150                                      | $^\circ\text{C}$ |
| $T_{stg}$                     |  | -55 ... +150                             | $^\circ\text{C}$ |
| $T_L$                         | Maximum Lead Temperature for Soldering   | 300                                      | $^\circ\text{C}$ |
| $T_{SOLD}$                    | 1.6 mm (0.062in.) from Case for 10s  | 260                                      | $^\circ\text{C}$ |
| $M_d$                         | Mounting Torque  | 1.13 / 10                                | Nm/lb.in         |
| <b>Weight</b>                 |  | 3.0                                      | g                |

**Features**

- Plastic Overmolded Tab
- Optimized for Low Conduction Losses
- Square RBSOA
- International Standard Package

**Advantages**

- High Power Density
- Extremely Rugged
- Low Gate Drive Requirement

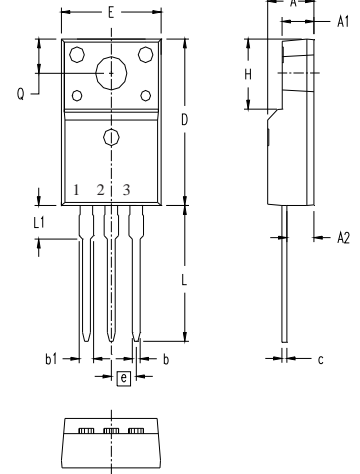
**Applications**

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- Inrush Current Protection Circuits

| Symbol        | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified) | Characteristic Values |      |                                       |
|---------------|---|-----------------------|------|---------------------------------------|
|               |   | Min.                  | Typ. | Max.                                  |
| $BV_{CES}$    | $I_C = 250\mu\text{A}$ , $V_{GE} = 0V$                                      | 600                   |      | V                                     |
| $V_{GE(th)}$  | $I_C = 250\mu\text{A}$ , $V_{CE} = V_{GE}$                                  | 3.0                   |      | 5.0 V                                 |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 125^\circ\text{C}$             |                       |      | 25 $\mu\text{A}$<br>250 $\mu\text{A}$ |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$  |                       |      | $\pm 100$ nA                          |
| $V_{CE(sat)}$ | $I_C = 24A$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 125^\circ\text{C}$          |                       | 1.3  | 1.4 V<br>V                            |

| Symbol Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) |  | Characteristic Values |                         |      |
|--|--|-----------------------|-------------------------|------|
|  |  | Min.                  | Typ.                    | Max. |
| $g_{fs}$   | $I_C = 24\text{A}, V_{CE} = 10\text{V}, \text{Note 1}$   | 17                    | 30                      | S    |
| $C_{ies}$  | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$   |                       | 1790                    | pF   |
| $C_{oes}$  |  |                       | 100                     | pF   |
| $C_{res}$  |  |                       | 26                      | pF   |
| $Q_{g(on)}$  | $I_C = 24\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$  |                       | 66                      | nC   |
| $Q_{ge}$   |  |                       | 13                      | nC   |
| $Q_{gc}$   |  |                       | 24                      | nC   |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 24\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 480\text{V}, R_G = 10\Omega$<br>Note 2  |                       | 18                      | ns   |
| $t_{ri}$   |  |                       | 26                      | ns   |
| $E_{on}$   |  |                       | 0.7                     | mJ   |
| $t_{d(off)}$   |  |                       | 300                     | ns   |
| $t_{fi}$   |  |                       | 260                     | ns   |
| $E_{off}$  |  |                       | 2.4                     | mJ   |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = 24\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 480\text{V}, R_G = 10\Omega$<br>Note 2 |                       | 20                      | ns   |
| $t_{ri}$   |  |                       | 26                      | ns   |
| $E_{on}$   |  |                       | 1.4                     | mJ   |
| $t_{d(off)}$   |  |                       | 470                     | ns   |
| $t_{fi}$   |  |                       | 400                     | ns   |
| $E_{off}$  |  |                       | 4.2                     | mJ   |
| $R_{thJC}$   |  | 0.50                  | 1.94 $^\circ\text{C/W}$ |      |
| $R_{thCS}$   |  |                       |                         |      |

## OVERMOLDED TO-220 (IXGP...M)



Terminals: 1 - Gate  
2 - Collector  
3 - Emitter

| SYM             | INCHES   |      | MILLIMETERS |       |
|-----------------|----------|------|-------------|-------|
|                 | MIN      | MAX  | MIN         | MAX   |
| A               | .177     | .193 | 4.50        | 4.90  |
| A1              | .092     | .108 | 2.34        | 2.74  |
| A2              | .101     | .117 | 2.56        | 2.96  |
| b               | .028     | .035 | 0.70        | 0.90  |
| b1              | .050     | .058 | 1.27        | 1.47  |
| c               | .018     | .024 | 0.45        | 0.60  |
| D               | .617     | .633 | 15.67       | 16.07 |
| E               | .392     | .408 | 9.96        | 10.36 |
| e               | .100 BSC |      | 2.54 BSC    |       |
| H               | .255     | .271 | 6.48        | 6.88  |
| L               | .499     | .523 | 12.68       | 13.28 |
| L1              | .119     | .135 | 3.03        | 3.43  |
| $\varnothing P$ | .121     | .129 | 3.08        | 3.28  |
| Q               | .126     | .134 | 3.20        | 3.40  |

### Notes:

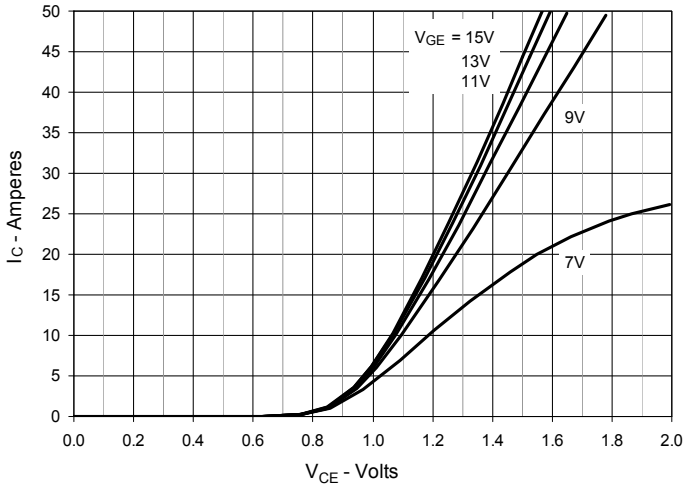
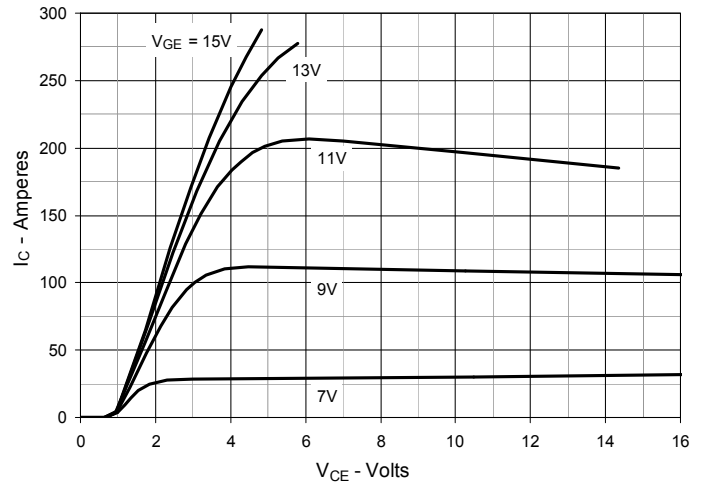
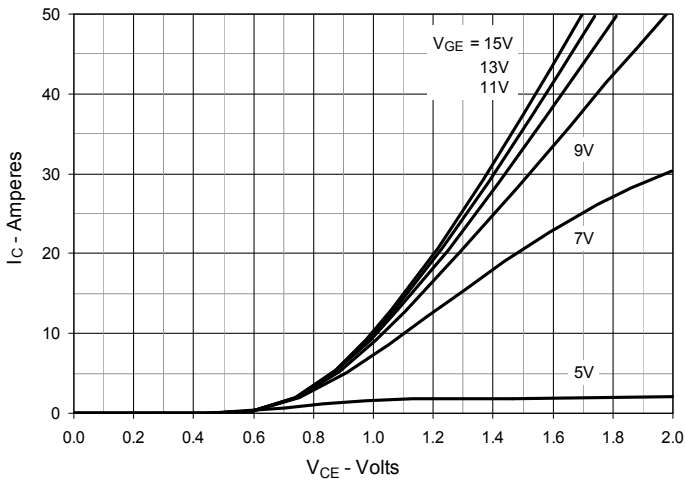
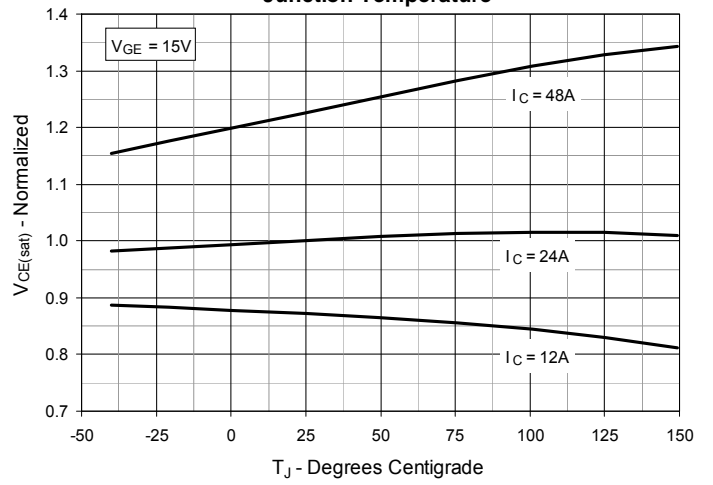
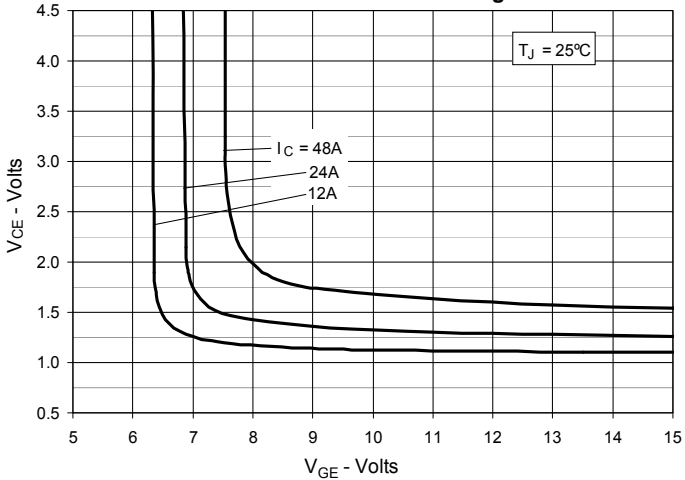
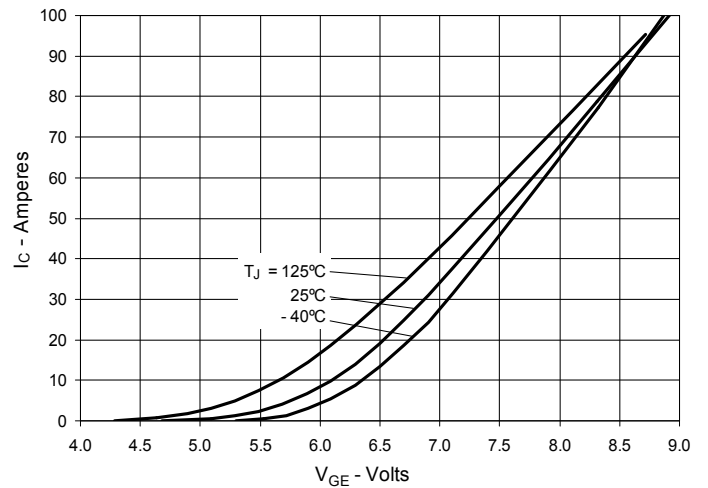
1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}(\text{clamp})$ ,  $T_J$  or  $R_G$ .

### ADVANCE TECHNICAL INFORMATION

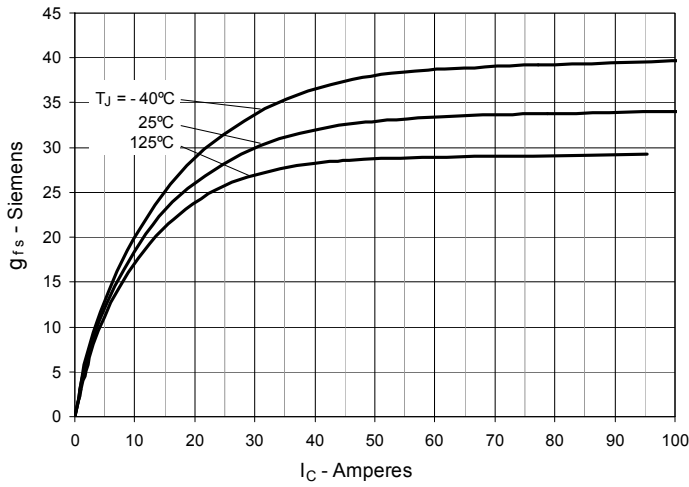
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

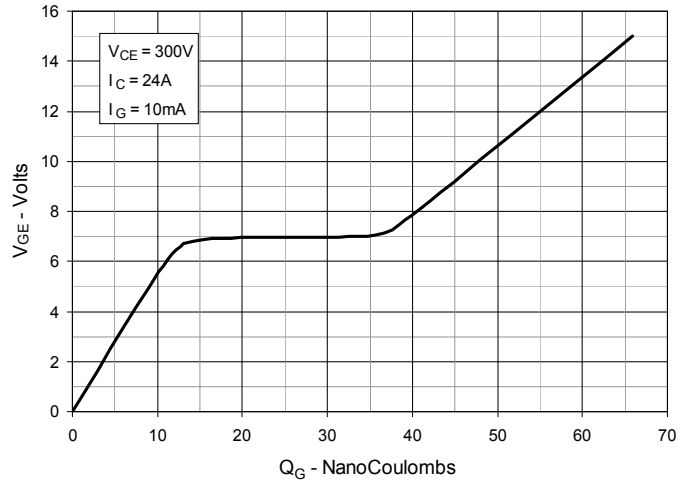
|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** 

**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**

**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**

**Fig. 6. Input Admittance**


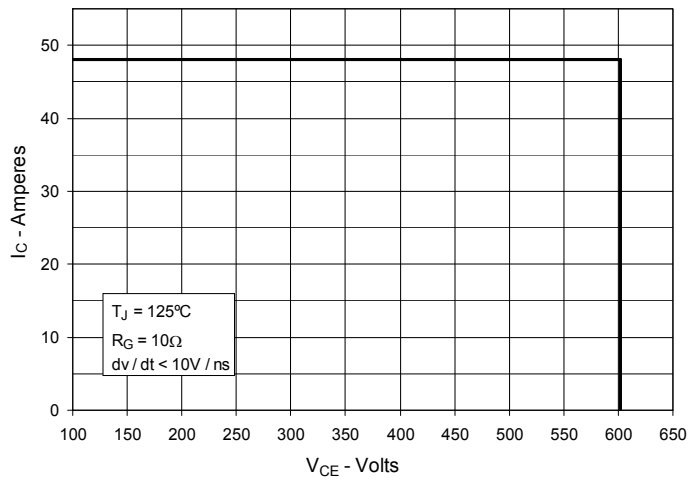
**Fig. 7. Transconductance**



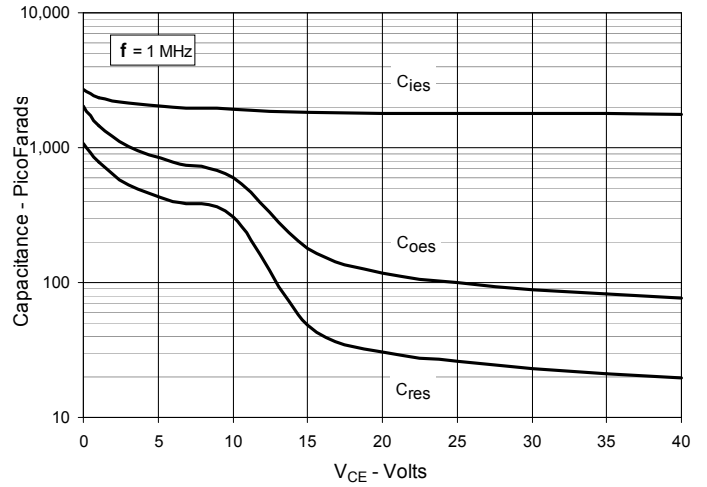
**Fig. 8. Gate Charge**



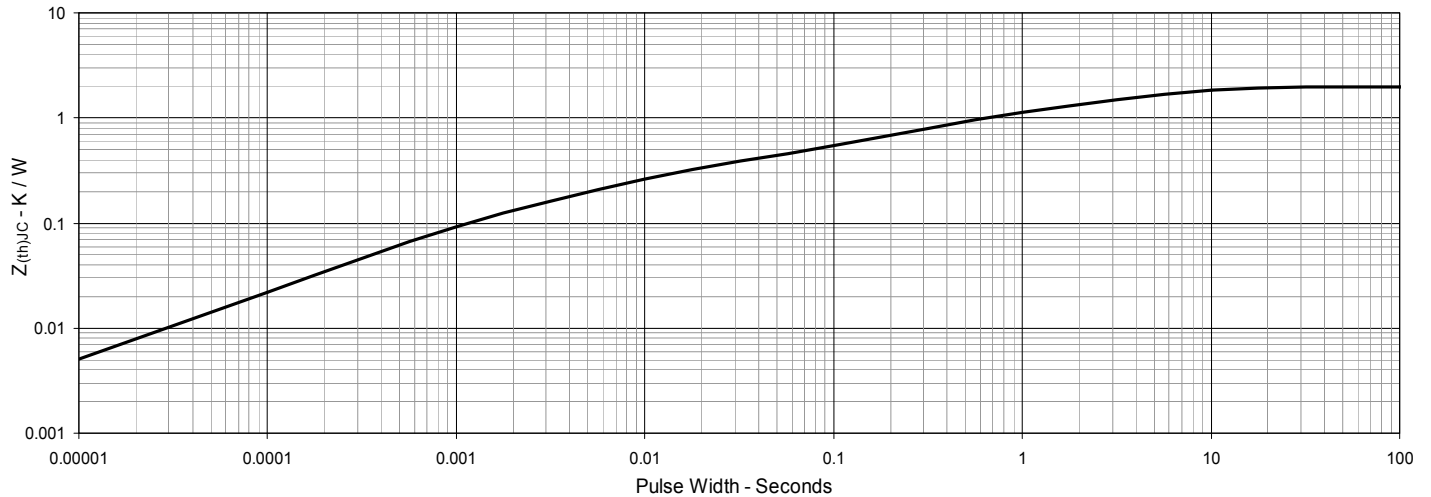
**Fig. 9. Reverse-Bias Safe Operating Area**



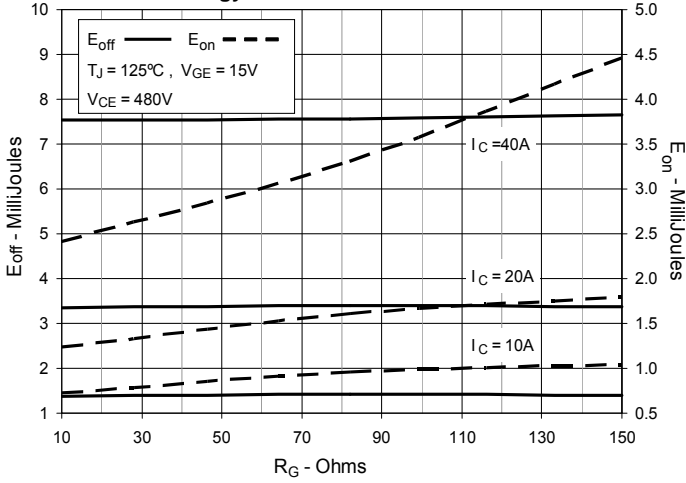
**Fig. 10. Capacitance**



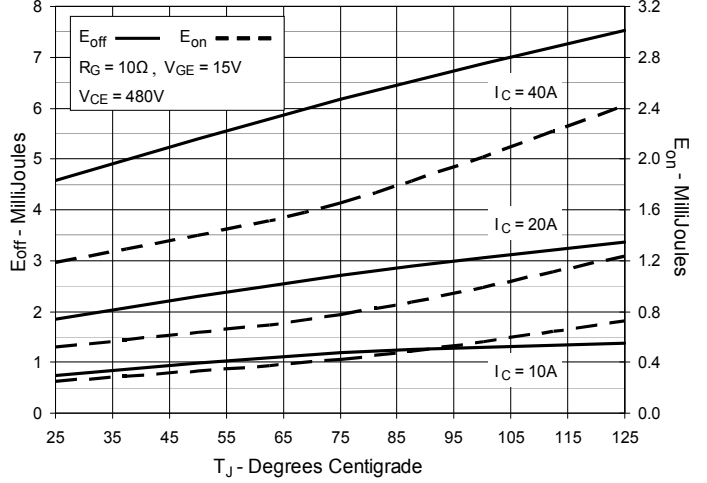
**Fig. 11. Maximum Transient Thermal Impedance**



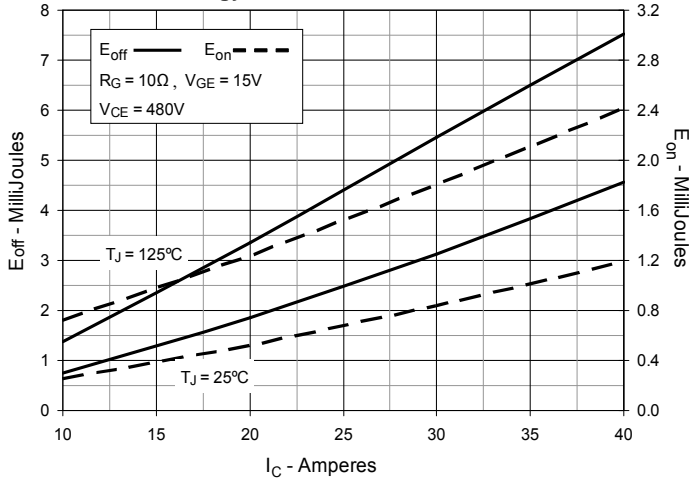
**Fig. 12. Inductive Switching  
Energy Loss vs. Gate Resistance**



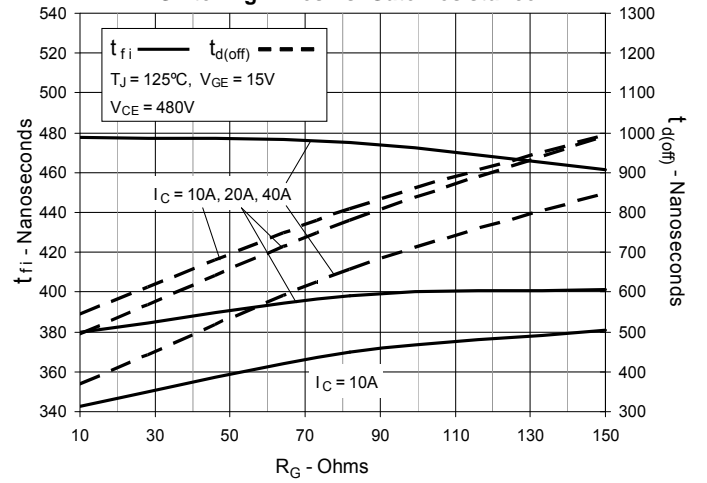
**Fig. 13. Inductive Switching  
Energy Loss vs. Junction Temperature**



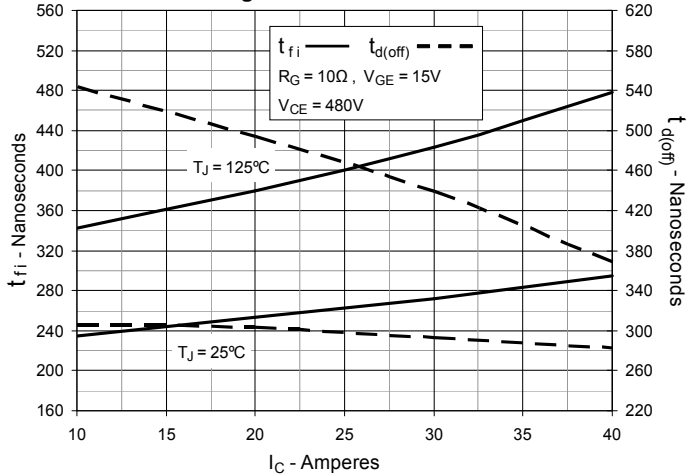
**Fig. 14. Inductive Switching  
Energy Loss vs. Collector Current**



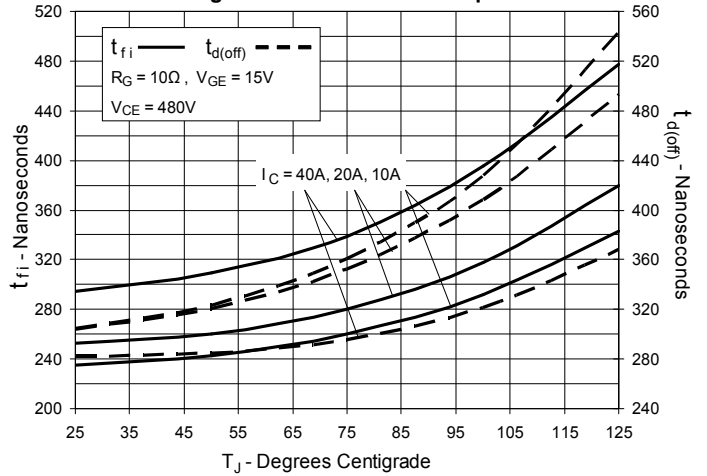
**Fig. 15. Inductive Turn-off  
Switching Times vs. Gate Resistance**



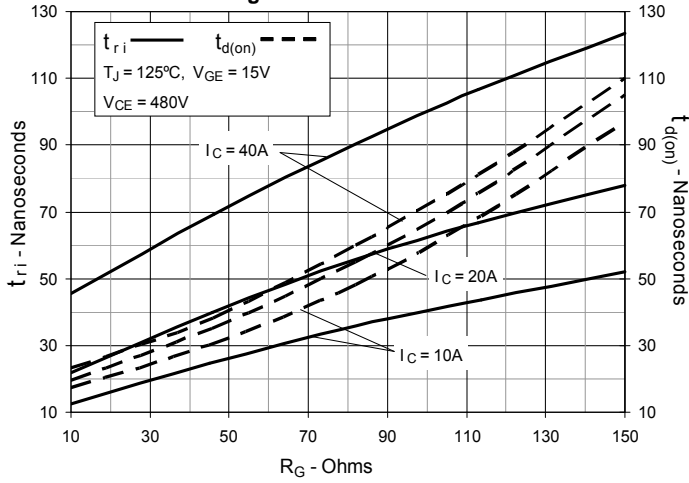
**Fig. 16. Inductive Turn-off  
Switching Times vs. Collector Current**



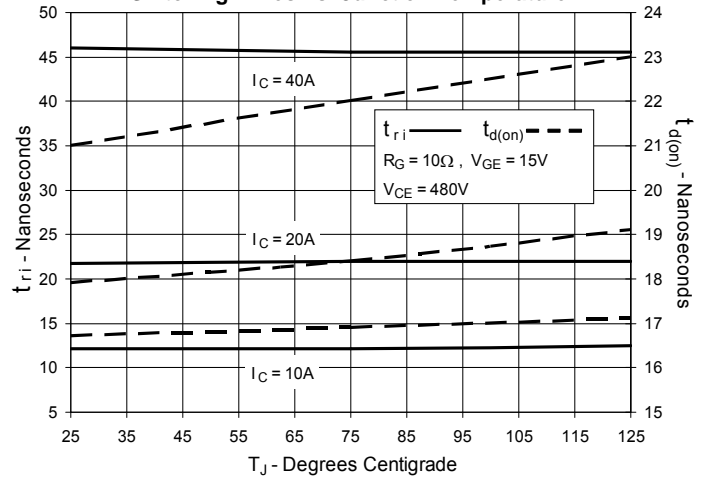
**Fig. 17. Inductive Turn-off  
Switching Times vs. Junction Temperature**



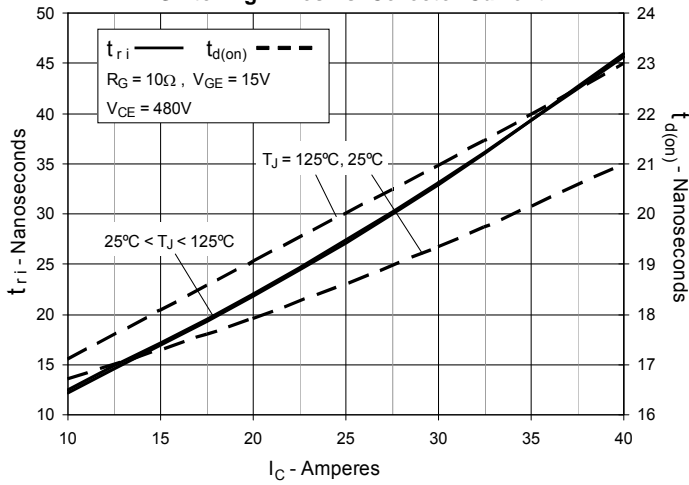
**Fig. 18. Inductive Turn-on**  
**Switching Times vs. Gate Resistance**



**Fig. 19. Inductive Turn-on**  
**Switching Times vs. Junction Temperature**



**Fig. 20. Inductive Turn-on**  
**Switching Times vs. Collector Current**





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